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SEMICONDUCTOR PHYSICS

092001 Dielectric confinement on exciton binding energy and nonlinear optical properties in a strained $\text{Zn}_{1-x_{\text{in}}}\text{Mg}_{x_{\text{in}}}\text{Se}/\text{Zn}_{1-x_{\text{out}}}\text{Mg}_{x_{\text{out}}}\text{Se}$ quantum well (7 pages)

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Said Benramache, Boubaker Benhaoua, and Foued Chabane

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S. S. Dhasade, S. H. Han, and V. J. Fulari

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Liu Tingliang, He Xulin, Zhang Jingquan, Feng Lianghuan, Wu Lili, Li Wei, Zeng Guanggen, and Li Bing

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Jiang Ran, Meng Lingguo, Zhang Xijian, Hyung-Suk Jung, and Cheol Seong Hwang

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Gu Chengyan, Lee Chengming, and Liu Xianglin

SEMICONDUCTOR DEVICES

094001 A fuzzy-logic-based approach to accurate modeling of a double gate MOSFET for nanoelectronic circuit design (7 pages)

F. Djeffal, A. Ferdi, and M. Chahdi

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Xu Wenqing, Qu Shengchun, Wang Kefan, Bi Yu, Liu Kong, and Wang Zhanguo

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Zhang Guoqing, Han Dejun, Zhu Changjun, and Zhai Xuejun

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Wang Jianhui, Wang Xinhua, Pang Lei, Chen Xiaojuan, Jin Zhi, and Liu Xinyu

(Continued on inside back cover)

- 094005** A strained Si-channel NMOSFET with low field mobility enhancement of about 140% using a SiGe virtual substrate (4 pages)
Cui Wei, Tang Zhaohuan, Tan Kaizhou, Zhang Jing, Zhong Yi, Hu Huiyong, Xu Shiliu, Li Ping, and Hu Gangyi
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Jiao Jian, Tan Manqing, Zhao Miao, and Chang Jinlong
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Xing Zhao, Jia Rui, Ding Wuchang, Meng Yanlong, Jin Zhi, and Liu Xinyu
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Zhang Zuwei, Wen Zhiyu, Shang Zhengguo, Li Dongling, and Hu Jing

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Guo Rui and Zhang Haiying
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Chen Honglei, Wu Dong, Shen Yanzhao, and Xu Jun
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Yang Zhaonian, Liu Hongxia, Li Li, and Zhuo Qingqing
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Shu Chen, Xu Jun, Ye Fan, and Ren Junyan